

Table of Contents

1 Features	1	6.12 Typical Characteristics	13
2 Applications	1	7 Parameter Measurement Information	14
3 Description	1	8 Detailed Description	16
4 Revision History	2	8.1 Overview	16
5 Pin Configuration and Functions	4	8.2 Functional Block Diagram	16
6 Specifications	7	8.3 Feature Description	16
6.1 Absolute Maximum Ratings	7	8.4 Device Functional Modes	18
6.2 ESD Ratings	7	9 Application and Implementation	19
6.3 Recommended Operating Conditions: SN74LVCH245A	8	9.1 Application Information	19
6.4 Recommended Operating Conditions: SN54LVCH245A	9	9.2 Typical Application	19
6.5 Thermal Information	9	10 Power Supply Recommendations	20
6.6 Electrical Characteristics: SN74LVCH245A	10	11 Layout	21
6.7 Electrical Characteristics: SN54LVCH245A	11	11.1 Layout Guidelines	21
6.8 Switching Characteristics: SN74LVCH245A, –40°C TO 85°C	12	11.2 Layout Example	21
6.9 Switching Characteristics: SN74LVCH245A, –40°C TO 125°C	12	12 Device and Documentation Support	22
6.10 Switching Characteristics: SN54LVCH245A	13	12.1 Related Links	22
6.11 Operating Characteristics	13	12.2 Trademarks	22
		12.3 Electrostatic Discharge Caution	22
		12.4 Glossary	22
		13 Mechanical, Packaging, and Orderable Information	22

4 Revision History

Changes from Revision P (July 2014) to Revision Q	Page
• Changed part number column to include specific orderable parts.	1
• Removed package name GQN.	6
• Added ZXY package pinout section.	6
• Changed Handling Ratings to ESD ratings.	7
• Deleted storage temperature from ESD Ratings table.	7
• Changed only include commercial device specifications in this table.	10
• Added new table for military device specifications.	11
• Deleted bulleted list of features.	16
• Added Output Types, Input Types, Clamp Diode Structure, and Special Features sections.	16

Changes from Revision O (December 2005) to Revision P	Page
• Updated document to new TI data sheet standards.	1
• Deleted Ordering Information table.	1
• Updated I _{off} Feature bullet.	1
• Added Military Disclaimer to Features list.	1
• Added Applications.	1
• Added Device Information table.	1
• Added Handling Ratings table.	7
• Changed MAX operating temperature to 125°C.	8
• Added Thermal Information table.	9
• Added –40°C TO 125°C to Electrical Characteristics table.	10
• Added data to –40°C TO 85°C Switching Characteristics table.	12
• Added Switching Characteristics table for –40°C to 125°C for SN74LVCH245A.	12

• Added data to Operating Characteristics table.	13
• Added Typical Characteristics.	13
• Added Detailed Description section.....	16
• Added Application and Implementation section.....	19

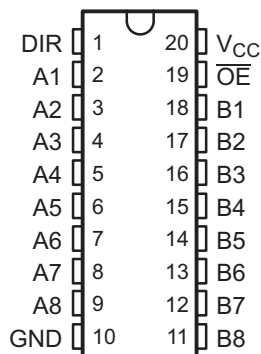
SN54LVCH245A, SN74LVCH245A

SCES008Q – JULY 1995 – REVISED SEPTEMBER 2018

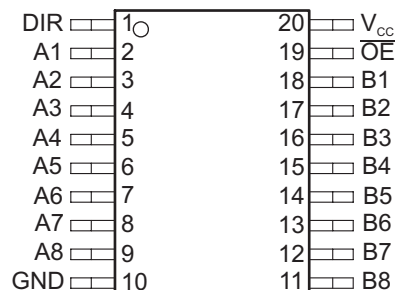
www.ti.com

5 Pin Configuration and Functions

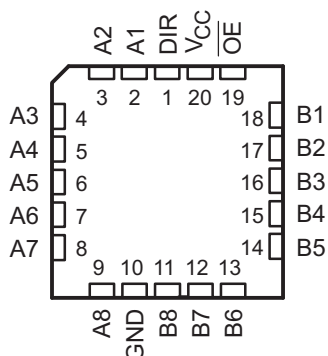
SN54LVCH245A
20-Pin J or W Package
Top View



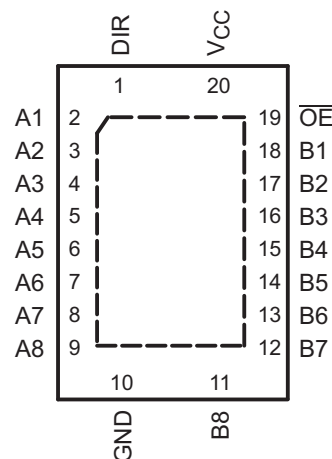
SN74LVCH245A
20-Pin Count DB, DGV, DW, NS or PW Package
Top View



SN54LVCH245A
20-Pin Count FK Package
Top View



SN74LVCH245A
20-Pin Count RGY Package
Top View

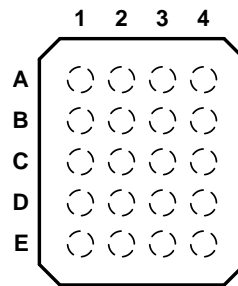


Pin Functions

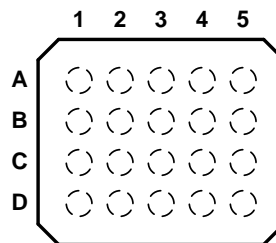
PIN		I/O	DESCRIPTION
NO.	NAME		
1	DIR	I	Direction select
2	A1	I/O	A1 input or output
3	A2	I/O	A2 input or output
4	A3	I/O	A3 input or output
5	A4	I/O	A4 input or output
6	A5	I/O	A5 input or output
7	A6	I/O	A6 input or output
8	A7	I/O	A7 input or output
9	A8	I/O	A8 input or output
10	GND	—	Ground
11	Y8	I/O	Y8 input or output
12	Y7	I/O	Y7 input or output
13	Y6	I/O	Y6 input or output
14	Y5	I/O	Y5 input or output
15	Y4	I/O	Y4 input or output
16	Y3	I/O	Y3 input or output
17	Y2	I/O	Y2 input or output
18	Y1	I/O	Y1 input or output
19	$\overline{\text{OE}}$	I	Output enable, active low
20	V _{CC}	—	Positive Supply

SN54LVCH245A, SN74LVCH245A

SCES008Q – JULY 1995 – REVISED SEPTEMBER 2018

www.ti.com
**ZQN PACKAGE
(TOP VIEW)**

Pin Assignments: ZQN Package

	1	2	3	4
A	A1	DIR	V _{CC}	$\overline{\text{OE}}$
B	A3	B2	A2	B1
C	A5	A4	B4	B3
D	A7	B6	A6	B5
E	GND	A8	B8	B7

**ZXY PACKAGE
(TOP VIEW)**

Pin Assignments: ZXY Package

	1	2	3	4	5
A	A7	A6	A4	A2	DIR
B	A8	A5	A3	A1	V _{CC}
C	GND	B6	B4	B2	$\overline{\text{OE}}$
D	B8	B7	B5	B3	B1

6 Specifications

6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

		MIN	MAX	UNIT
Supply voltage range, V_{CC}		–0.5	6.5	V
Input voltage range, V_I ⁽²⁾		–0.5	6.5	V
Voltage range applied to any output in the high-impedance or power-off state, V_O ⁽²⁾		–0.5	6.5	V
Voltage range applied to any output in the high or low state, V_O ⁽²⁾⁽³⁾		–0.5	$V_{CC} + 0.5$	V
Input clamp current, I_{IK}	$V_I < 0$		–50	mA
Output clamp current, I_{OK}	$V_O < 0$		–50	mA
Continuous output current, I_O			±50	mA
Continuous current through V_{CC} or GND			±100	mA
Operating virtual junction temperature, T_j			150	°C
Storage temperature range, T_{stg}		–65	150	°C

- (1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
- (3) The value of V_{CC} is provided in the *Recommended Operating Conditions* table.

6.2 ESD Ratings

		MIN	MAX	UNIT
$V_{(ESD)}$ Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins ⁽¹⁾	0	2000	V
	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins ⁽²⁾	0	1500	

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

SN54LVCH245A, SN74LVCH245A

SCES008Q – JULY 1995 – REVISED SEPTEMBER 2018

www.ti.com
6.3 Recommended Operating Conditions: SN74LVCH245A

 over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage	Operating	1.65	3.6	V
		Data retention only	1.5		
V _{IH}	High-level input voltage	V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}		V
		V _{CC} = 2.3 V to 2.7 V	1.7		
		V _{CC} = 2.7 V to 3.6 V	2		
V _{IL}	Low-level input voltage	V _{CC} = 1.65 V to 1.95 V		0.35 × V _{CC}	V
		V _{CC} = 2.3 V to 2.7 V		0.7	
		V _{CC} = 2.7 V to 3.6 V		0.8	
V _I	Input voltage		0	5.5	V
V _O	Output voltage	High or low state	0	V _{CC}	V
		Tri-state	0	5.5	
I _{OH}	High-level output current	V _{CC} = 1.65 V		–4	mA
		V _{CC} = 2.3 V		–8	
		V _{CC} = 2.7 V		–12	
		V _{CC} = 3 V		–24	
I _{OL}	Low-level output current	V _{CC} = 1.65 V		4	mA
		V _{CC} = 2.3 V		8	
		V _{CC} = 2.7 V		12	
		V _{CC} = 3 V		24	
Δt/Δv	Input transition rise or fall rate			10	ns/V
T _A	Operating free-air temperature		–40	125	°C

(1) All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. For more information, see the [Implications of Slow or Floating CMOS Inputs](#) application report.

6.4 Recommended Operating Conditions: SN54LVCH245A

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage	Operating	2	3.6	V
		Data retention only	1.5		
V _{IH}	High-level input voltage	V _{CC} = 1.65 V to 1.95 V			V
		V _{CC} = 2.3 V to 2.7 V			
		V _{CC} = 2.7 V to 3.6 V	2		
V _{IL}	Low-level input voltage	V _{CC} = 1.65 V to 1.95 V			V
		V _{CC} = 2.3 V to 2.7 V			
		V _{CC} = 2.7 V to 3.6 V		0.8	
V _I	Input voltage		0	5.5	V
V _O	Output voltage	High or low state	0	V _{CC}	V
		Tri-state	0	5.5	
I _{OH}	High-level output current	V _{CC} = 1.65 V			mA
		V _{CC} = 2.3 V			
		V _{CC} = 2.7 V		–12	
		V _{CC} = 3 V		–24	
I _{OL}	Low-level output current	V _{CC} = 1.65 V			mA
		V _{CC} = 2.3 V			
		V _{CC} = 2.7 V		12	
		V _{CC} = 3 V		24	
Δt/Δv	Input transition rise or fall rate			10	ns/V
T _A	Operating free-air temperature		–55	125	°C

(1) All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. For more information, see the [Implications of Slow or Floating CMOS Inputs](#) application report.

6.5 Thermal Information

THERMAL METRIC ⁽¹⁾		SN74LVCH245A								UNIT
		DB	DGV	DW	NS	PW	RGY	ZQN	ZXY	
		20 PINS								
R _{θJA}	Junction-to-ambient thermal resistance	94.5	114.7	88.3	74.7	102.5	41.4	129.3	123.5	°C/W
R _{θJC(top)}	Junction-to-case (top) thermal resistance	56.2	29.8	51.1	40.5	35.9	47.7	75.3	58.9	
R _{θJB}	Junction-to-board thermal resistance	49.7	56.2	50.9	42.3	53.5	17.1	77.6	74.8	
Ψ _{JT}	Junction-to-top characterization parameter	18.1	0.8	20.0	14.3	2.2	1.4	2.6	2.0	
Ψ _{JB}	Junction-to-board characterization parameter	49.2	55.5	50.5	41.9	52.9	17.1	73.2	74.4	
R _{θJC(bot)}	Junction-to-case (bottom) thermal resistance	n/a	n/a	n/a	n/a	n/a	9.8	n/a	n/a	

(1) For more information about traditional and new thermal metrics, see the [IC Package Thermal Metrics](#) application report.

SN54LVCH245A, SN74LVCH245A

SCES008Q – JULY 1995 – REVISED SEPTEMBER 2018

www.ti.com
6.6 Electrical Characteristics: SN74LVCH245A

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		V _{CC}	–40°C TO 85°C		–40°C TO 125°C		UNIT
				MIN	TYP ⁽¹⁾	MAX	MIN	
V _{OH} High-level output voltage	I _{OH} = –100 μA		1.65 V to 3.6 V	V _{CC} – 0.2		V _{CC} – 0.2		V
	I _{OH} = –4 mA		1.65 V	1.2		1.2		
	I _{OH} = –8 mA		2.3 V	1.7		1.7		
	I _{OH} = –12 mA		2.7 V	2.2		2.2		
			3 V	2.4		2.4		
	I _{OH} = –24 mA		3 V	2.2		2.2		
V _{OL} Low-level output voltage	I _{OL} = 100 μA		1.65 V to 3.6 V	0.2		0.20		V
	I _{OL} = 4 mA		1.65 V	0.45		0.45		
	I _{OL} = 8 mA		2.3 V	0.7		0.7		
	I _{OL} = 12 mA		2.7 V	0.4		0.4		
	I _{OL} = 24 mA		3 V	0.55		0.55		
I _I Input current	Control inputs: V _I = 0 to 5.5 V		3.6 V	±5		±5		μA
I _{off} Input and output power-off leakage current	V _I or V _O = 5.5 V		0 V	±10		±20		μA
I _{I(hold)} Input hold current	V _I = 0.58 V		1.65 V	25		25		μA
	V _I = 1.07 V			–25		–25		
	V _I = 0.7 V		2.3 V	45		45		
	V _I = 1.7 V			–45		–45		
	V _I = 0.8 V		3 V	75		75		
	V _I = 2 V			–75		–75		
	V _I = 0 to 3.6 V ⁽²⁾		3.6 V	±500		±500		
I _{OZ} ⁽³⁾ High-impedance state output current	V _O = 0 V or (V _{CC} to 5.5 V)		2.3 V to 3.6 V	±5		±15		μA
I _{CC} Supply current	V _I = V _{CC} or GND	I _O = 0	3.6 V	10		10		μA
	3.6 V ≤ V _I ≤ 5.5 V ⁽⁴⁾	I _O = 0	3.6 V	10		10		
ΔI _{CC} Supply-current change	One input at V _{CC} – 0.6 V, other inputs at V _{CC} or GND		2.7 V to 3.6 V	500		500		μA
C _I Input capacitance	Control inputs: V _I = V _{CC} or GND		3.3 V	4				pF
C _{io} Input and output capacitance	A or B port: V _O = V _{CC} or GND		3.3 V	5.50				pF

 (1) All typical values are V_{CC} = 3.3 V, T_A = 25°C.

(2) The bus-hold maximum dynamic current requirement to switch the input from one state to another state.

 (3) For the total leakage current in an I/O port, see the I_{I(hold)} specification for the input voltage condition 0 V < V_I < V_{CC}, and the I_{OZ} specification for the input voltage conditions V_I = 0 V or V_I = V_{CC} to 5.5 V. A bus-hold current with an input voltage greater than V_{CC} is negligible.

(4) This only applies when in a disabled state.

6.7 Electrical Characteristics: SN54LVCH245A

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS	V _{CC}	MIN	TYP ⁽¹⁾	MAX	UNIT
V _{OH}	High-level output voltage	I _{OH} = –100 µA	2.7 V to 3.6 V	V _{CC} – 0.2			V
		I _{OH} = –12 mA	2.7 V	2.2			
			3 V	2.4			
		I _{OH} = –24 mA	3 V	2.2			
V _{OL}	Low-level output voltage	I _{OL} = 100 µA	2.7 V to 3.6 V			0.2	V
		I _{OL} = 12 mA	2.7 V			0.4	
		I _{OL} = 24 mA	3 V			0.55	
I _I	Input current	Control inputs: V _I = 0 to 5.5 V	3.6 V			±5	µA
I _{I(hold)}	Input hold current	V _I = 0.8 V	3 V	75			µA
		V _I = 2 V		–75			
		V _I = 0 to 3.6 V ⁽²⁾	3.6 V			±500	
I _{OZ} ⁽³⁾	High-impedance state output current	V _O = 0 V or (V _{CC} to 5.5 V)	2.3 V to 3.6 V			±15	µA
I _{CC}	Supply current	V _I = V _{CC} or GND	I _O = 0	3.6 V		10	µA
		3.6 V ≤ V _I ≤ 5.5 V ⁽⁴⁾	I _O = 0	3.6 V		10	
ΔI _{CC}	Supply-current change	One input at V _{CC} – 0.6 V, other inputs at V _{CC} or GND	2.7 V to 3.6 V			500	µA
C _i	Input capacitance	Control inputs: V _I = V _{CC} or GND	3.3 V		4	12	pF
C _{io}	Input and output capacitance	A or B port: V _O = V _{CC} or GND	3.3 V		5.5	12	pF

(1) All typical values are V_{CC} = 3.3 V, T_A = 25°C.

(2) The bus-hold maximum dynamic current requirement to switch the input from one state to another state.

(3) For the total leakage current in an I/O port, see the I_{I(hold)} specification for the input voltage condition 0 V < V_I < V_{CC}, and the I_{OZ} specification for the input voltage conditions V_I = 0 V or V_I = V_{CC} to 5.5 V. A bus-hold current with an input voltage greater than V_{CC} is negligible.

(4) This only applies when in a disabled state.

SN54LVCH245A, SN74LVCH245A

SCES008Q – JULY 1995 – REVISED SEPTEMBER 2018

www.ti.com
6.8 Switching Characteristics: SN74LVCH245A, –40°C TO 85°C

over recommended operating free-air temperature range (unless otherwise noted) (see [Parameter Measurement Information](#))

PARAMETER	TEST CONDITIONS	$V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CC} = 2.7\text{ V}$		$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{pd} Propagation delay time	Input A or B to B or A output		12.7		8.3		7.3	1.5	6.3	ns
t_{en} Enable time	Input \overline{OE} to A or B output		15.3		10.5		9.5	1.5	8.5	ns
t_{dis} Disable time	Input \overline{OE} to A or B output		17		9.5		8.5	1.5	7.5	ns
$t_{sk(o)}$ Output skew			1		1		1		1	ns

6.9 Switching Characteristics: SN74LVCH245A, –40°C TO 125°C

over recommended operating free-air temperature range (unless otherwise noted) (see [Parameter Measurement Information](#))

PARAMETER	TEST CONDITIONS	$V_{CC} = 1.8\text{ V} \pm 0.15\text{ V}$		$V_{CC} = 2.5\text{ V} \pm 0.2\text{ V}$		$V_{CC} = 2.7\text{ V}$		$V_{CC} = 3.3\text{ V} \pm 0.3\text{ V}$		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{pd} Propagation delay time	Input A or B to B or A output		13.7		9.1		7.8	1.5	6.7	ns
t_{en} Enable time	Input \overline{OE} to A or B output		16.8		12		10	1.5	9.1	ns
t_{dis} Disable time	Input \overline{OE} to A or B output		18		10.5		8.7	1.5	7.8	ns
t_{PLH} Propagation delay time (low-level to high-level output)	Input A to Y output $C_L = 50\text{ pF}$	5.4	7.5	1	8.5	1	8.5	1	9.5	ns
t_{PHL} Propagation delay time (high-level to low-level output)	Input A to Y output $C_L = 50\text{ pF}$	5.4	7.5	1	8.5	1	8.5	1	9.5	
t_{PZH} Enable time (to high level)	Input \overline{OE} to Y output $C_L = 50\text{ pF}$	6.2	9.3	1	10.5	1	10.5	1	11.5	ns
t_{PZL} Enable time (to low level)	Input \overline{OE} to Y output $C_L = 50\text{ pF}$	6.2	9.3	1	10.5	1	10.5	1	11.5	
t_{PHZ} Disable time (to high level)	Input \overline{OE} to Y output $C_L = 50\text{ pF}$	6.7	9.2	1	10.5	1	10.5	1	11	ns
t_{PLZ} Disable time (to low level)	Input \overline{OE} to Y output $C_L = 50\text{ pF}$	6.7	9.2	1	10.5	1	10.5	1	11	
$t_{sk(o)}$ Output skew	$C_L = 50\text{ pF}$		1 ⁽¹⁾		1		1		1	ns

(1) With products compliant to MIL-PRF-38535, this parameter does not apply.

6.10 Switching Characteristics: SN54LVCH245A

over recommended operating free-air temperature range (unless otherwise noted) (see [Parameter Measurement Information](#))

PARAMETER	TEST CONDITIONS	V _{CC} = 2.7 V		V _{CC} = 3.3 V ± 0.3 V		UNIT
		MIN	MAX	MIN	MAX	
t _{pd}	Propagation delay time	8		1	7	ns
t _{en}	Enable time	9.5		1	8.5	ns
t _{dis}	Disable time	8.5		1	7.5	ns

6.11 Operating Characteristics

T_A = 25°C

PARAMETER		TEST CONDITIONS		V _{CC} = 1.8 V	V _{CC} = 2.5 V	V _{CC} = 3.3 V	UNIT
				TYP	TYP	TYP	
C _{pd}	Power dissipation capacitance per transceiver	f = 10 MHz	Outputs enabled	42	43	47	pF
			Outputs disabled	1	1	2	

6.12 Typical Characteristics

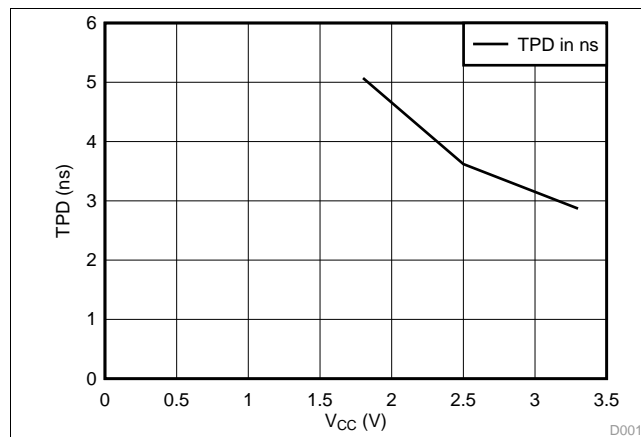


Figure 1. SN74LVCH245A TPD Across V_{CC} at 25°C

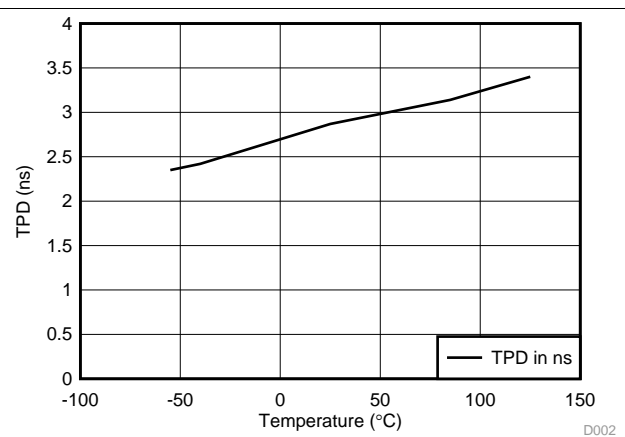


Figure 2. SN74LVCH245A TPD Across Temperature at 3.3 V

7 Parameter Measurement Information

- (1) C_L includes probe and jig capacitance.

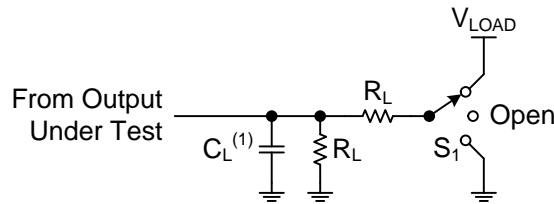


Figure 3. Load Circuit

Table 1. Test Load Switch Position

TEST	S_1
t_{PLH} / t_{PHL}	Open
t_{PLZ} / t_{PZL}	V_{LOAD}
t_{PHZ} / t_{PZH}	GND

Table 2. Test and Measurement Conditions

V_{CC}	INPUTS		V_M	V_{LOAD}	C_L	R_L	V_A
	V_I	t_r/t_f					
$1.8\text{ V} \pm 0.15\text{ V}$	V_{CC}	$\leq 2\text{ ns}$	$V_{CC} / 2$	$2 \times V_{CC}$	30 pF	1 k Ω	0.15 V
$2.5\text{ V} \pm 0.2\text{ V}$	V_{CC}	$\leq 2\text{ ns}$	$V_{CC} / 2$	$2 \times V_{CC}$	30 pF	500 Ω	0.15 V
2.7 V	2.7 V	$\leq 2.5\text{ ns}$	1.5 V	6 V	50 pF	500 Ω	0.3 V
$3.3\text{ V} \pm 0.3\text{ V}$	2.7 V	$\leq 2.5\text{ ns}$	1.5 V	6 V	50 pF	500 Ω	0.3 V

- (1) Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control.
Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
- (2) t_{PZL} and t_{PZH} are the same as t_{en} .
- (3) t_{PLZ} and t_{PHZ} are the same as t_{dis} .

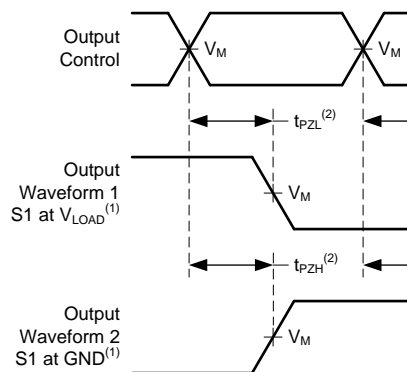


Figure 4. Voltage Waveforms Enable and Disable Times Low- and High-Level Enabling

- (1) t_{PLH} and t_{PHL} are the same as t_{pd} .

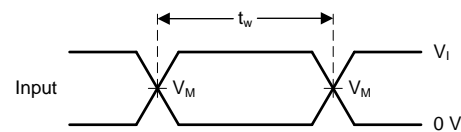


Figure 5. Voltage Waveforms Pulse Duration

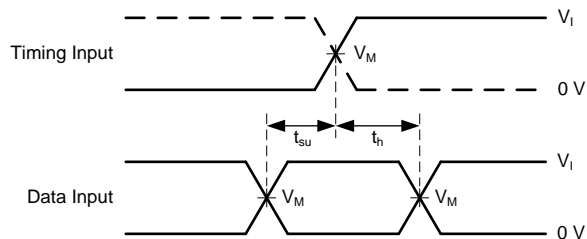


Figure 6. Voltage Waveforms Setup and Hold Times

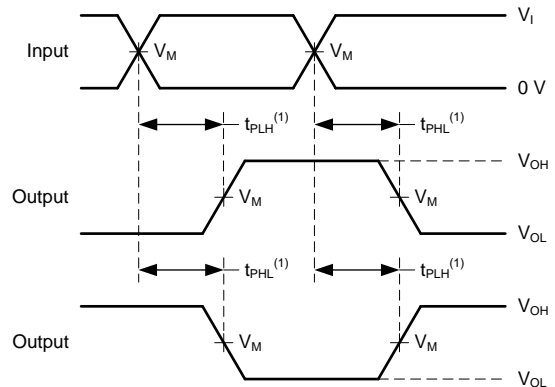


Figure 7. Voltage Waveforms Propagation Delay Times Inverting and Noninverting Outputs

8 Detailed Description

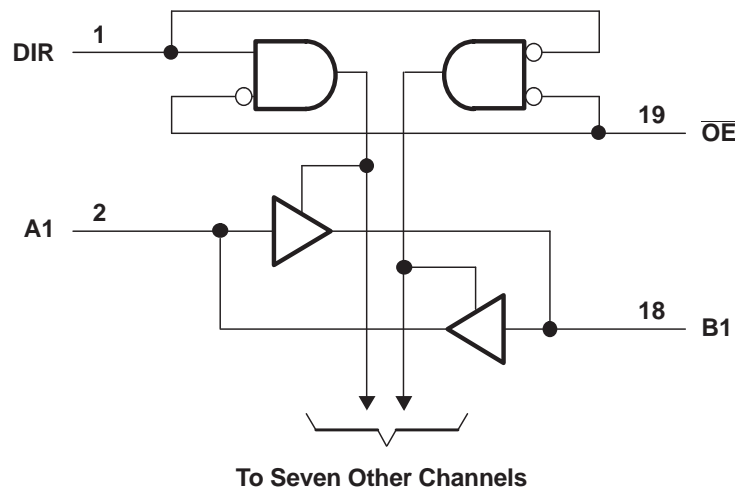
8.1 Overview

The SN54LVCH245A octal bus transceiver is designed for a 2.7-V to 3.6-V V_{CC} operation, and the SN74LVCH245A octal bus transceiver is designed for a 1.65-V to 3.6-V V_{CC} operation. Inputs can be driven from either the 3.3-V or 5-V devices. This feature allows the use of these devices as translators in a mixed 3.3-V or 5-V system environment.

These devices are designed for asynchronous communication between data buses. These devices transmit data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable (\overline{OE}) input can be used to disable the device, so the buses are effectively isolated.

These devices are fully specified for partial-power-down applications using I_{off} . The I_{off} circuitry disables the outputs which prevents damaging current backflow through the devices when they are powered down. To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver. Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level. The bus-hold circuitry is part of the input circuit and is not disabled by \overline{OE} or DIR, so use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

8.2 Functional Block Diagram



8.3 Feature Description

8.3.1 Balanced High-Drive CMOS Push-Pull Outputs

A balanced output allows the device to sink and source similar currents. The high drive capability of this device creates fast edges into light loads, so routing and load conditions should be taken into consideration to prevent ringing. Additionally, the outputs of this device are capable of driving larger currents than the device can sustain without being damaged. The power output of the device must be limited to avoid thermal runaway and damage caused by over-current. Follow the electrical and thermal limits defined in the [Absolute Maximum Ratings](#) at all times.

8.3.2 Standard CMOS Inputs

Standard CMOS inputs are high impedance, and these inputs are typically modeled as a resistor in parallel with the input capacitance given in the [Electrical Characteristics: SN74LVCH245A](#). The worst case resistance is calculated with the maximum input voltage, given in the [Absolute Maximum Ratings](#), and the maximum input leakage current, given in the [Electrical Characteristics: SN74LVCH245A](#), using ohm's law ($R = V \div I$).

Feature Description (continued)

Signals applied to the inputs need to have fast edge rates, as defined by $\Delta t/\Delta v$ in [Recommended Operating Conditions: SN54LVCH245A](#) to avoid excessive current consumption and oscillations. If a slow or noisy input signal is required, a device with a Schmitt-trigger input should be used to condition the input signal prior to the standard CMOS input.

8.3.3 Negative Clamping Diodes

The inputs and outputs to this device have negative clamping diodes as depicted in [Figure 8](#).

CAUTION

Voltages beyond the values specified in the [Absolute Maximum Ratings](#) table can cause damage to the device. The input negative-voltage and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

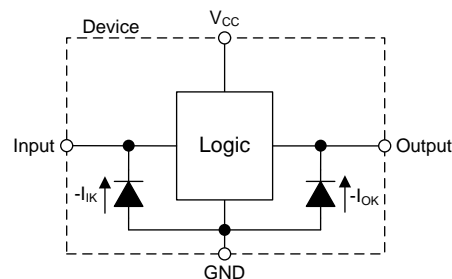


Figure 8. Electrical Placement of Clamping Diodes for Each Input and Output

8.3.4 Bus-Hold Data Inputs

Each data input on this device includes a weak latch that maintains a valid logic level on the input. The state of these latches is unknown at startup and remains unknown until the input has been forced to a valid high or low state. After data has been sent through a channel, the latch then maintains the previous state on the input if the line is left floating.

NOTE

It is highly recommended to not use pull-up or pull-down resistors together with a bus-hold input.

Bus-hold data inputs prevent floating inputs on this device. The [Implications of Slow or Floating CMOS Inputs application report](#) explains the problems associated with leaving CMOS inputs floating.

These latches remain active at all times, independent of output disable signals such as direction selection or output enables.

The [Bus-Hold Circuit application report](#) has additional details regarding bus-hold inputs.

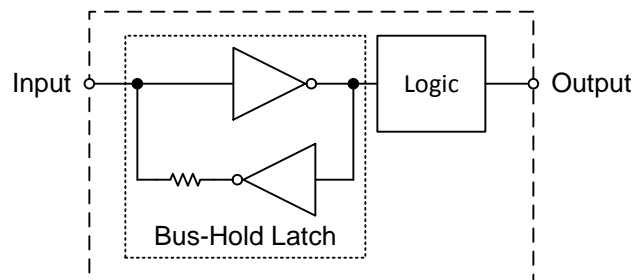


Figure 9. Simplified Schematic For Device With Bus-Hold Data Inputs

Feature Description (continued)

8.3.5 Partial Power Down (I_{off})

The inputs and outputs for this device enter a high-impedance state when the supply voltage is 0 V. The maximum leakage into or out of any input or output pin on the device is specified by I_{off} in the [Electrical Characteristics: SN74LVCH245A](#).

8.3.6 Over-voltage Tolerant Inputs

Input signals to this device can be driven above the supply voltage, as long as the input signals remain below the maximum input voltage value specified in the [Recommended Operating Conditions: SN54LVCH245A](#).

8.3.7 Output Enable

This device has an output enable (OE) pin that functions according to . When the outputs of the device are disabled, they are placed into a high impedance state where it will neither source nor sink current. High-impedance outputs are also commonly referred to as three-state or tri-state outputs. The maximum leakage for the output in this state is defined by I_{OZ} in the [Electrical Characteristics: SN74LVCH245A](#) table.

8.4 Device Functional Modes

Table 3. Function Table

INPUTS		OPERATION
\overline{OE}	DIR	
L	L	B data to A bus
L	H	A data to B bus
H	X	Isolation

9 Application and Implementation

9.1 Application Information

The SN74LVCH245A device is a high-drive CMOS device with bus-hold inputs that can be used for a multitude of bus interface type applications where the data needs to be transmitted and received. The device's output can produce 24 mA of drive current at 3.3 V. Therefore, this device is ideal for driving multiple outputs and for high-speed applications up to 100 MHz. The inputs are 5.5-V tolerant which allows the devices to translate down to V_{CC} .

Figure 10 shows a typical down-translation application in which the device is being used with a fixed direction to reduce an 8-bit 5-V bus to an 8-bit 1.8-V bus.

Figure 11 shows a typical application in which a bus must switch directions for data transfer between a master and a slave device. The SN74LVCH245A allows either V_{CC1} or V_{CC3} to be shut down completely because it has bus-hold inputs that maintains valid states on the floating lines. In this example, V_{CC1} , V_{CC2} , and V_{CC3} all have the same value, but each supply can be delivered by a separate source.

Figure 12 shows a functional diagram for a single channel of the device, including the bus-hold, direction, and output enable logic components. When the direction is set as 'A to B,' the buffer labeled 'A' is disabled and the buffer labeled 'B' is enabled. When the direction is set as 'B to A,' the buffer labeled 'B' is disabled and the buffer labeled 'A' is enabled. When the output enable pin is deasserted, the buffers labeled 'A' and 'B' are both disabled. The bus-hold circuitry remains active at all times.

9.2 Typical Application

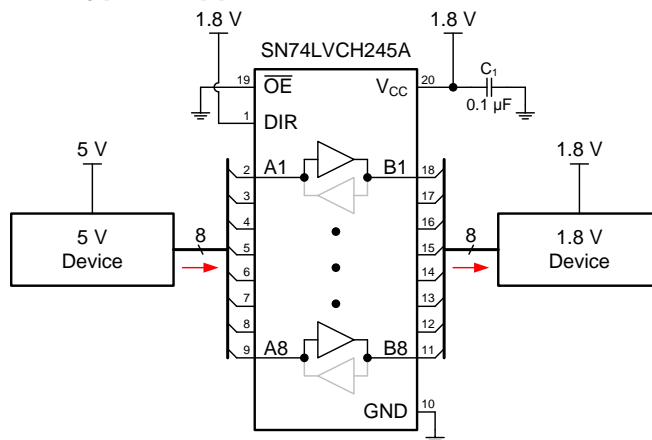


Figure 10. Typical Down-Translation Application

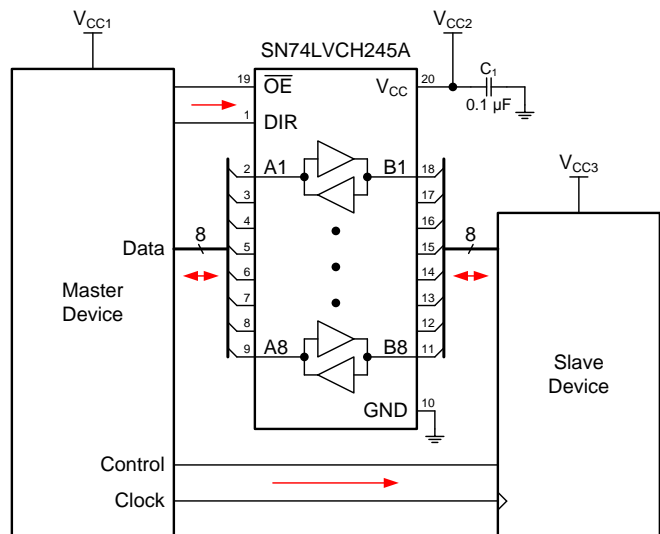


Figure 11. Typical Direction Controlled Application

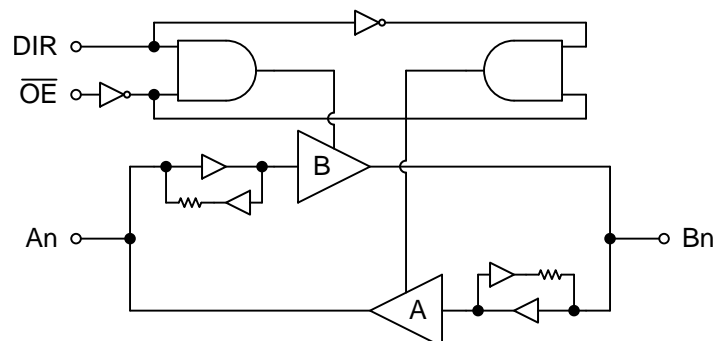


Figure 12. Equivalent Internal Schematic Including Bus-Hold Inputs

Typical Application (continued)

9.2.1 Design Requirements

This device uses CMOS technology and has a balanced output drive. Care should be taken to avoid bus contention because the device's output can drive currents that exceed maximum limits. The high drive also creates fast edges into light loads; therefore, routing and load conditions should be considered to prevent ringing.

This device has bus-hold inputs, which are always active regardless of DIR or \overline{OE} input values. For more information, refer to the [Bus-Hold Data Inputs](#).

9.2.2 Detailed Design Procedure

1. Recommended Input Conditions

- See $(\Delta t/\Delta V)$ in the [Recommended Operating Conditions: SN54LVCH245A](#) table for the input transition rate specification.
- See $(V_{IH}$ and $V_{IL})$ in the [Recommended Operating Conditions: SN54LVCH245A](#) table for the input voltage high level and input voltage low level specifications.
- The inputs are overvoltage tolerant. This allows them to rise up to 5.5 V at any valid V_{CC} .
- The inputs can be left floating. The internal bus-hold circuits maintains the last valid state at the inputs.

2. Recommended Output Conditions

- Do not exceed 25 mA per output and 50 mA in total for the device.
- Do not pull outputs above V_{CC} .

9.2.3 Application Curves

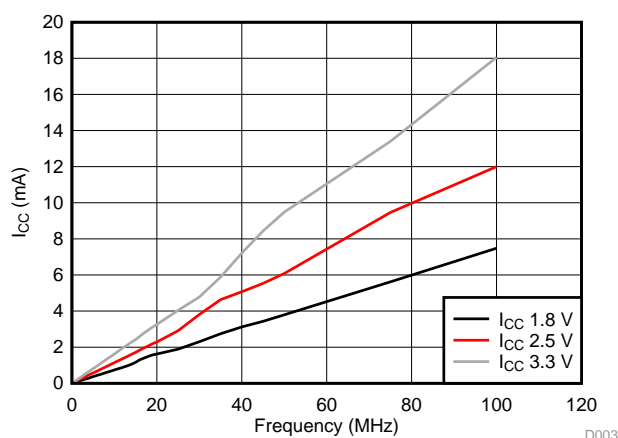


Figure 13. I_{CC} vs Frequency

10 Power Supply Recommendations

The [Recommended Operating Conditions: SN54LVCH245A](#) table shows the power supply can be any voltage between the minimum and maximum supply voltage rating that are listed.

Each V_{CC} pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1 μF is recommended; if there are multiple V_{CC} pins, then 0.01 μF or 0.022 μF is recommended for each power pin. It is acceptable to parallel multiple bypass capacitors to reject different noise frequencies. A 0.1 μF and a 1 μF are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

11 Layout

11.1 Layout Guidelines

When using multiple-bit logic devices, inputs should never float.

In many cases, functions or parts of functions of digital logic devices are unused. For example, when two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Figure 14 specifies the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally, they will be tied to GND or V_{CC} , the deciding factor is based on whichever makes more sense or is more convenient at the time. It is generally acceptable to float outputs, unless the part is a transceiver. If the transceiver has an output enable pin, then asserting the output enable pin will disable the output section of the part. This will not disable the input section of the I/Os, so they cannot float when disabled.

11.2 Layout Example

Figure 14 shows an example layout for the ZXY package. This package has a 0.5-mm pitch and requires either micro-vias or very small traces to access the center pins. In this example, 4-mil vias with 10-mil pads are used to access the center pins. All pins are connected by 5-mil traces except for the supply pins which use 10-mil traces.

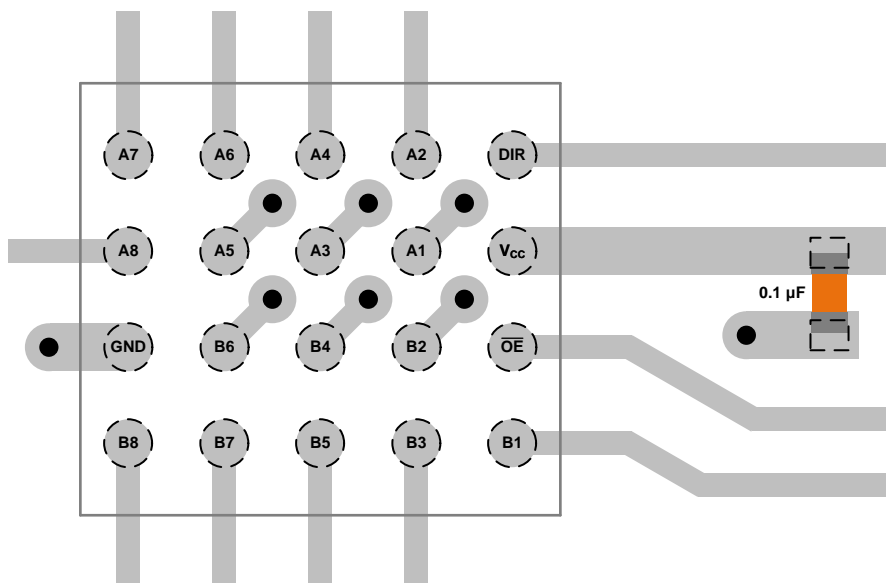


Figure 14. Example Layout of ZXY Package

12 Device and Documentation Support

12.1 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

Table 4. Related Links

PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY
SN54LVCH245A	Click here	Click here	Click here	Click here	Click here
SN74LVCH245A	Click here	Click here	Click here	Click here	Click here

12.2 Trademarks

All trademarks are the property of their respective owners.

12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

12.4 Glossary

[SLYZ022](#) — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

13 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9754301Q2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9754301Q2A SNJ54LVCH 245AFK	Samples
5962-9754301QRA	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9754301QR A SNJ54LVCH245AJ	Samples
5962-9754301QSA	ACTIVE	CFP	W	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9754301QS A SNJ54LVCH245AW	Samples
5962-9754301V2A	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962- 9754301V2A SNV54LVCH 245AFK	Samples
5962-9754301VRA	ACTIVE	CDIP	J	20	20	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9754301VR A SNV54LVCH245AJ	Samples
5962-9754301VSA	ACTIVE	CFP	W	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9754301VS A SNV54LVCH245AW	Samples
SN74LVCH245ADBR	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LCH245A	Samples
SN74LVCH245ADBRE4	ACTIVE	SSOP	DB	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LCH245A	Samples
SN74LVCH245ADGVR	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LCH245A	Samples
SN74LVCH245ADGVRE4	ACTIVE	TVSOP	DGV	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LCH245A	Samples
SN74LVCH245ADW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVCH245A	Samples
SN74LVCH245ADWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVCH245A	Samples
SN74LVCH245ADWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVCH245A	Samples

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
SN74LVCH245ANSR	ACTIVE	SO	NS	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LVCH245A	Samples
SN74LVCH245APW	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LCH245A	Samples
SN74LVCH245APWE4	ACTIVE	TSSOP	PW	20	70	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LCH245A	Samples
SN74LVCH245APWR	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU CU SN	Level-1-260C-UNLIM	-40 to 85	LCH245A	Samples
SN74LVCH245APWRE4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LCH245A	Samples
SN74LVCH245APWRG4	ACTIVE	TSSOP	PW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LCH245A	Samples
SN74LVCH245APWT	ACTIVE	TSSOP	PW	20	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	LCH245A	Samples
SN74LVCH245ARGYR	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LCH245A	Samples
SN74LVCH245ARGYRG4	ACTIVE	VQFN	RGY	20	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR	-40 to 85	LCH245A	Samples
SN74LVCH245AZQNR	ACTIVE	BGA MICROSTAR JUNIOR	ZQN	20	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	LCH245A	Samples
SN74LVCH245AZXYR	ACTIVE	BGA MICROSTAR JUNIOR	ZXY	20	2500	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM	-40 to 85	KH245A	Samples
SNJ54LVCH245AFK	ACTIVE	LCCC	FK	20	1	TBD	POST-PLATE	N / A for Pkg Type	-55 to 125	5962-9754301Q2A SNJ54LVCH245AFK	Samples
SNJ54LVCH245AJ	ACTIVE	CDIP	J	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9754301QR A SNJ54LVCH245AJ	Samples
SNJ54LVCH245AW	ACTIVE	CFP	W	20	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9754301QS A SNJ54LVCH245AW	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of ≤ 1000 ppm threshold. Antimony trioxide based flame retardants must also meet the ≤ 1000 ppm threshold requirement.

⁽³⁾ **MSL, Peak Temp.** - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

⁽⁵⁾ Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ **Lead/Ball Finish** - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF SN54LVCH245A, SN54LVCH245A-SP, SN74LVCH245A :

● Catalog: [SN74LVCH245A](#), [SN54LVCH245A](#)

● Military: [SN54LVCH245A](#)

● Space: [SN54LVCH245A-SP](#)

NOTE: Qualified Version Definitions:

-
- Catalog - TI's standard catalog product
 - Military - QML certified for Military and Defense Applications
 - Space - Radiation tolerant, ceramic packaging and qualified for use in Space-based application

TAPE AND REEL INFORMATION


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74LVCH245ADBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74LVCH245ADGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74LVCH245ADWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74LVCH245ANSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74LVCH245APWT	TSSOP	PW	20	250	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1
SN74LVCH245ARGYR	VQFN	RGY	20	3000	330.0	12.4	3.8	4.8	1.6	8.0	12.0	Q1
SN74LVCH245AZQNR	BGA MICROSTAR JUNIOR	ZQN	20	1000	330.0	12.4	3.3	4.3	1.6	8.0	12.0	Q1
SN74LVCH245AZXYR	BGA MICROSTAR JUNIOR	ZXY	20	2500	330.0	12.4	2.8	3.3	1.0	4.0	12.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74LVCH245ADBR	SSOP	DB	20	2000	367.0	367.0	38.0
SN74LVCH245ADGVR	TVSOP	DGV	20	2000	367.0	367.0	35.0
SN74LVCH245ADWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74LVCH245ANSR	SO	NS	20	2000	367.0	367.0	45.0
SN74LVCH245APWT	TSSOP	PW	20	250	367.0	367.0	38.0
SN74LVCH245ARGYR	VQFN	RGY	20	3000	367.0	367.0	35.0
SN74LVCH245AZQNR	BGA MICROSTAR JUNIOR	ZQN	20	1000	350.0	350.0	43.0
SN74LVCH245AZXYR	BGA MICROSTAR JUNIOR	ZXY	20	2500	350.0	350.0	43.0

J (R-GDIP-T**)

14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



PINS ** DIM	14	16	18	20
A	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC	0.300 (7,62) BSC
B MAX	0.785 (19,94)	.840 (21,34)	0.960 (24,38)	1.060 (26,92)
B MIN	—	—	—	—
C MAX	0.300 (7,62)	0.300 (7,62)	0.310 (7,87)	0.300 (7,62)
C MIN	0.245 (6,22)	0.245 (6,22)	0.220 (5,59)	0.245 (6,22)



4040083/F 03/03

- NOTES:
- A. All linear dimensions are in inches (millimeters).
 - B. This drawing is subject to change without notice.
 - C. This package is hermetically sealed with a ceramic lid using glass frit.
 - D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
 - E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

DGV (R-PDSO-G**)

PLASTIC SMALL-OUTLINE

24 PINS SHOWN



- NOTES: A. All linear dimensions are in millimeters.
 B. This drawing is subject to change without notice.
 C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
 D. Falls within JEDEC: 24/48 Pins – MO-153
 14/16/20/56 Pins – MO-194

PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



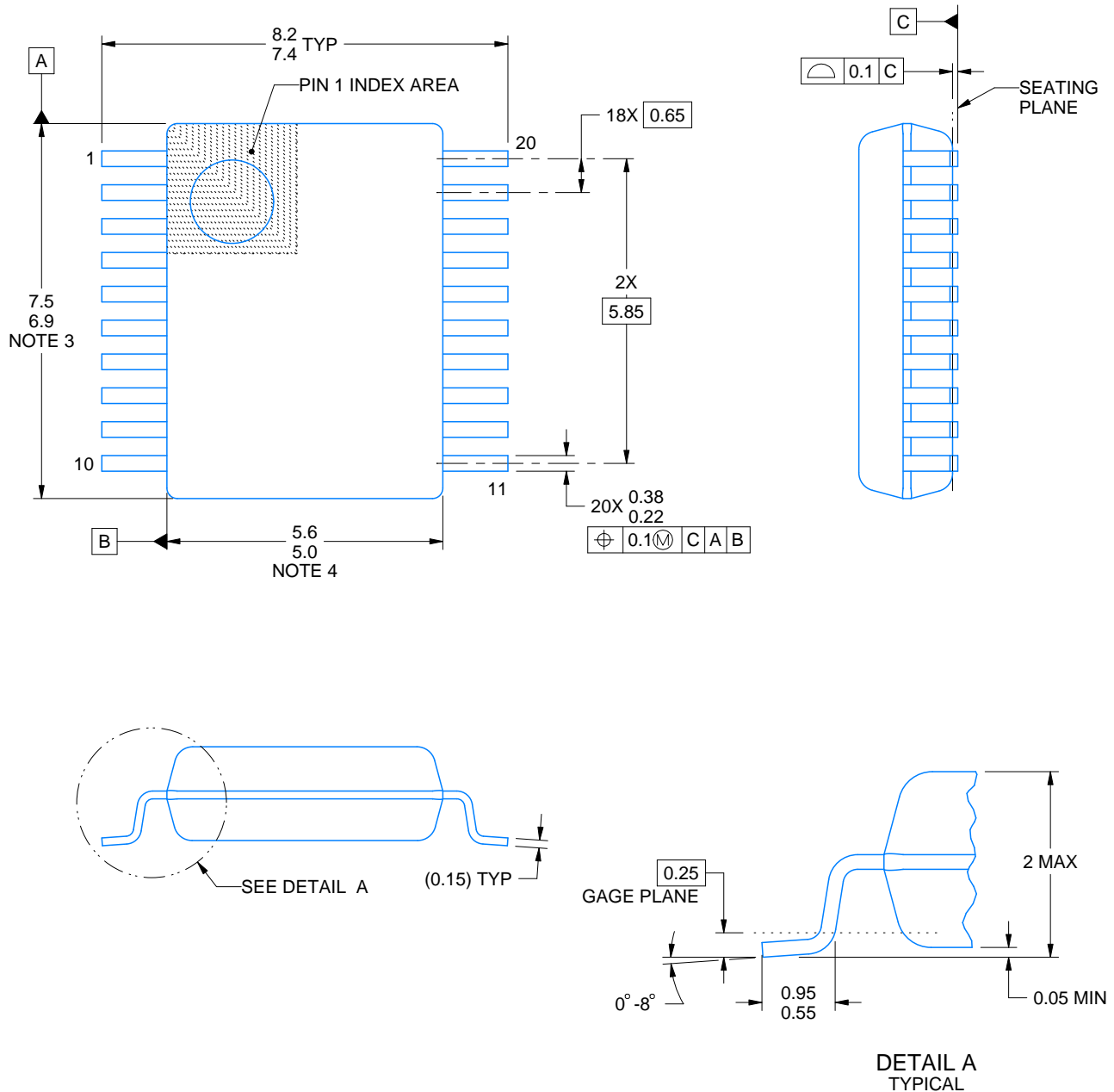
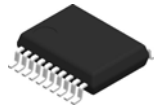
- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
 - D. Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
 - E. Falls within JEDEC MO-153

PW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Publication IPC-7351 is recommended for alternate design.
 - D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 - E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



4214851/A 12/2017

NOTES:

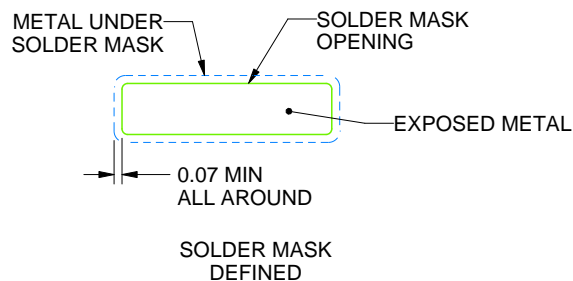
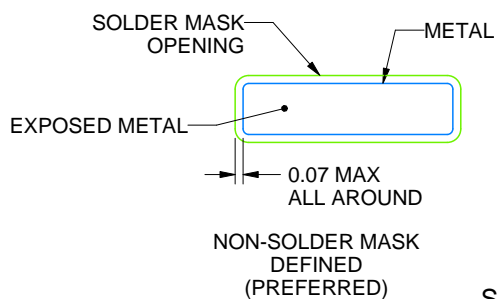
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
5. Reference JEDEC registration MO-150.

EXAMPLE BOARD LAYOUT

DB0020A

TSSOP - 2 mm max height

SMALL OUTLINE PACKAGE



SOLDER MASK DETAILS

4214851/A 12/2017

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DB0020A

TSSOP - 2 mm max height

SMALL OUTLINE PACKAGE



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE: 10X

4214851/A 12/2017

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

DW0020A**PACKAGE OUTLINE****SOIC - 2.65 mm max height**

SOIC



4220724/A 05/2016

NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
5. Reference JEDEC registration MS-013.

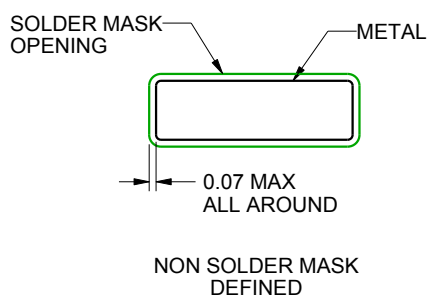
DW0020A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE
SCALE:6X



SOLDER MASK DETAILS

4220724/A 05/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

DW0020A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL
SCALE:6X

4220724/A 05/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

W (R-GDFP-F20)

CERAMIC DUAL FLATPACK

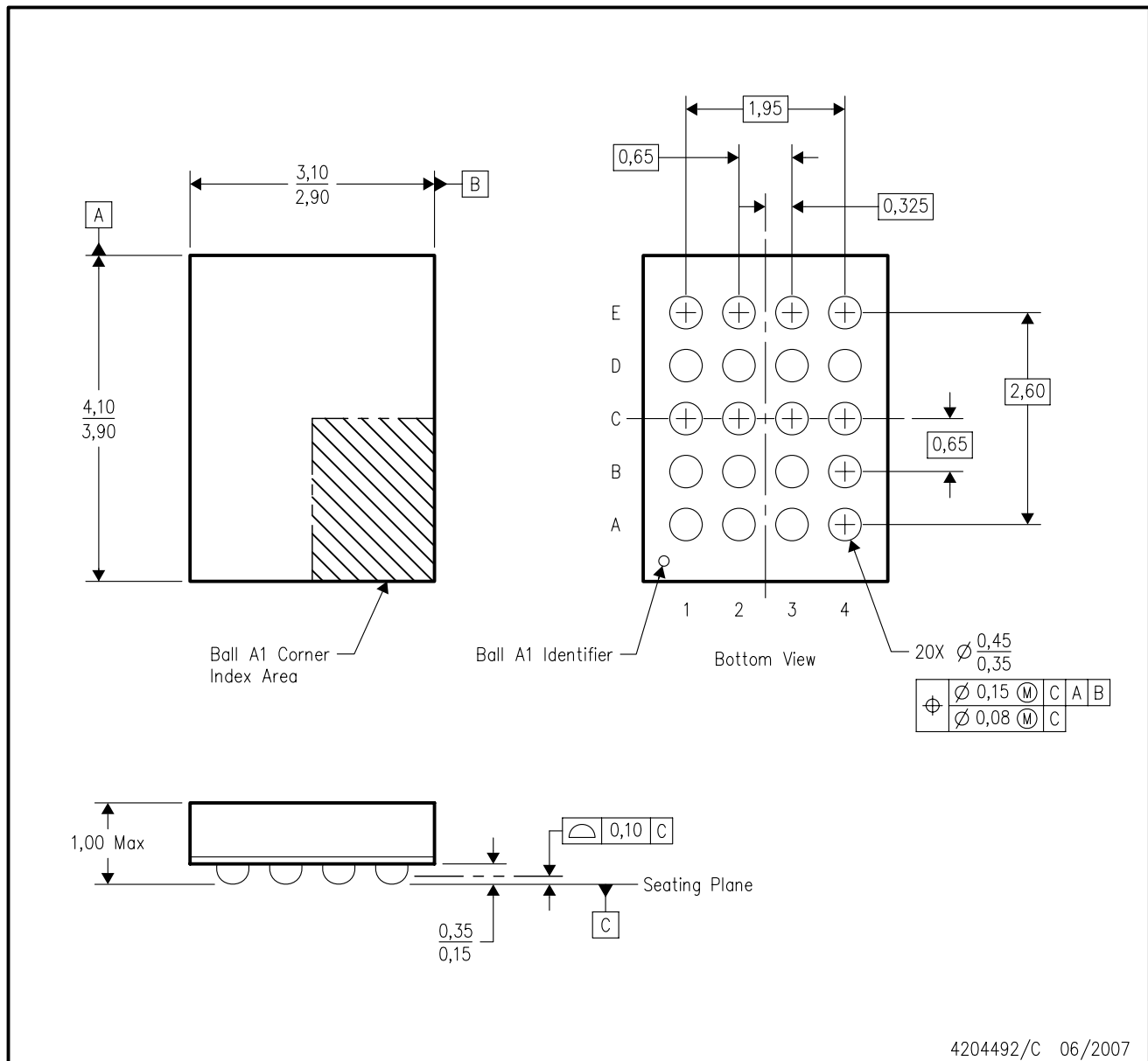


NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package can be hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only.
- E. Falls within Mil-Std 1835 GDFP2-F20

ZQN (R-PBGA-N20)

PLASTIC BALL GRID ARRAY



4204492/C 06/2007

- NOTES:
- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - B. This drawing is subject to change without notice.
 - C. Falls within JEDEC MO-285 variation BC-2.
 - D. This package is lead-free. Refer to the 20 GQN package (drawing 4200704) for tin-lead (SnPb).



VFBGA - 0.61 mm max height

PLASTIC BALL GRID ARRAY



1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

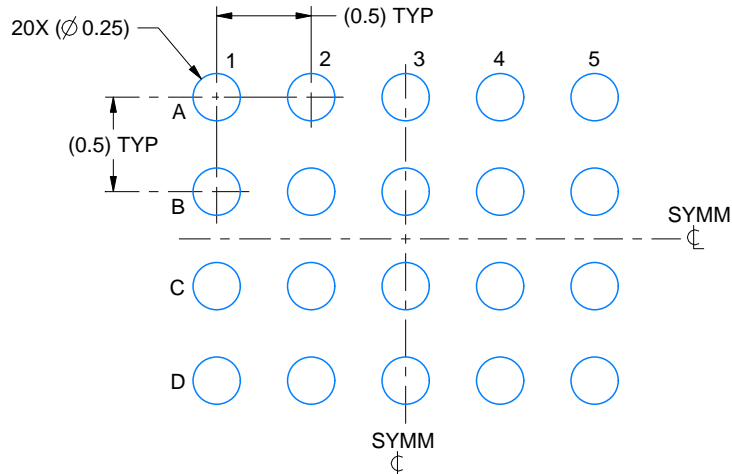
2. This drawing is subject to change without notice.

EXAMPLE BOARD LAYOUT

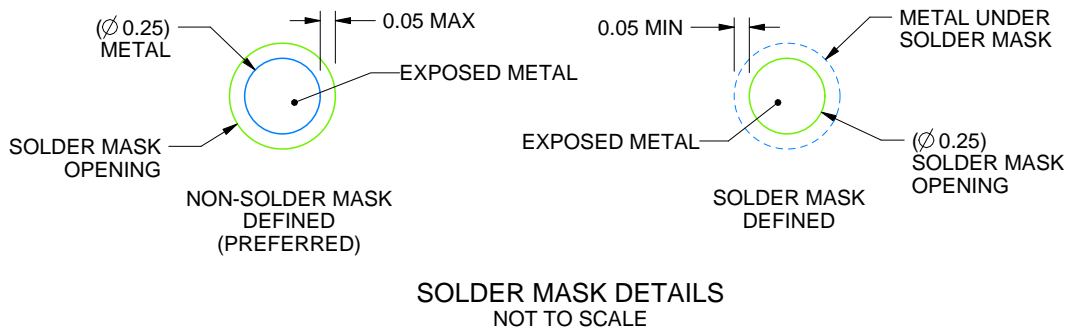
ZXY0020A

VFBGA - 0.61 mm max height

PLASTIC BALL GRID ARRAY



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:25X



4222996/A 12/2016

NOTES: (continued)

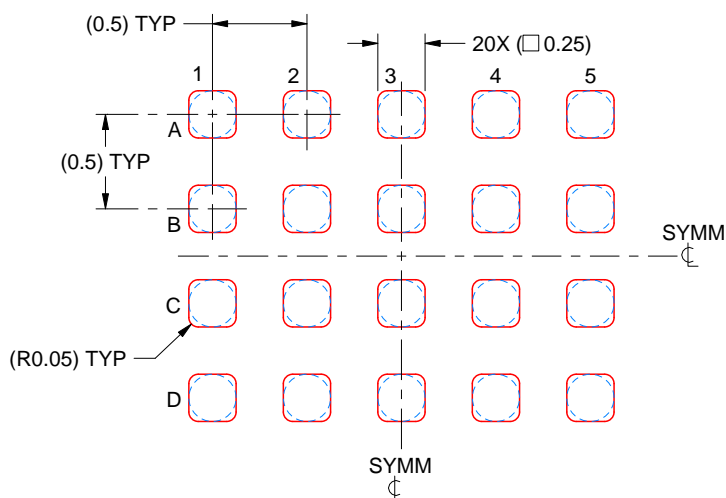
- Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For information, see Texas Instruments literature number SPRAA99 (www.ti.com/lit/spraa99).

EXAMPLE STENCIL DESIGN

ZXY0020A

VFBGA - 0.61 mm max height

PLASTIC BALL GRID ARRAY



SOLDER PASTE EXAMPLE
BASED ON 0.1 mm THICK STENCIL
SCALE: 25X

4222996/A 12/2016

NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.

FK (S-CQCC-N**)

LEADLESS CERAMIC CHIP CARRIER

28 TERMINAL SHOWN



NO. OF TERMINALS **	A		B	
	MIN	MAX	MIN	MAX
20	0.342 (8,69)	0.358 (9,09)	0.307 (7,80)	0.358 (9,09)
28	0.442 (11,23)	0.458 (11,63)	0.406 (10,31)	0.458 (11,63)
44	0.640 (16,26)	0.660 (16,76)	0.495 (12,58)	0.560 (14,22)
52	0.740 (18,78)	0.761 (19,32)	0.495 (12,58)	0.560 (14,22)
68	0.938 (23,83)	0.962 (24,43)	0.850 (21,6)	0.858 (21,8)
84	1.141 (28,99)	1.165 (29,59)	1.047 (26,6)	1.063 (27,0)

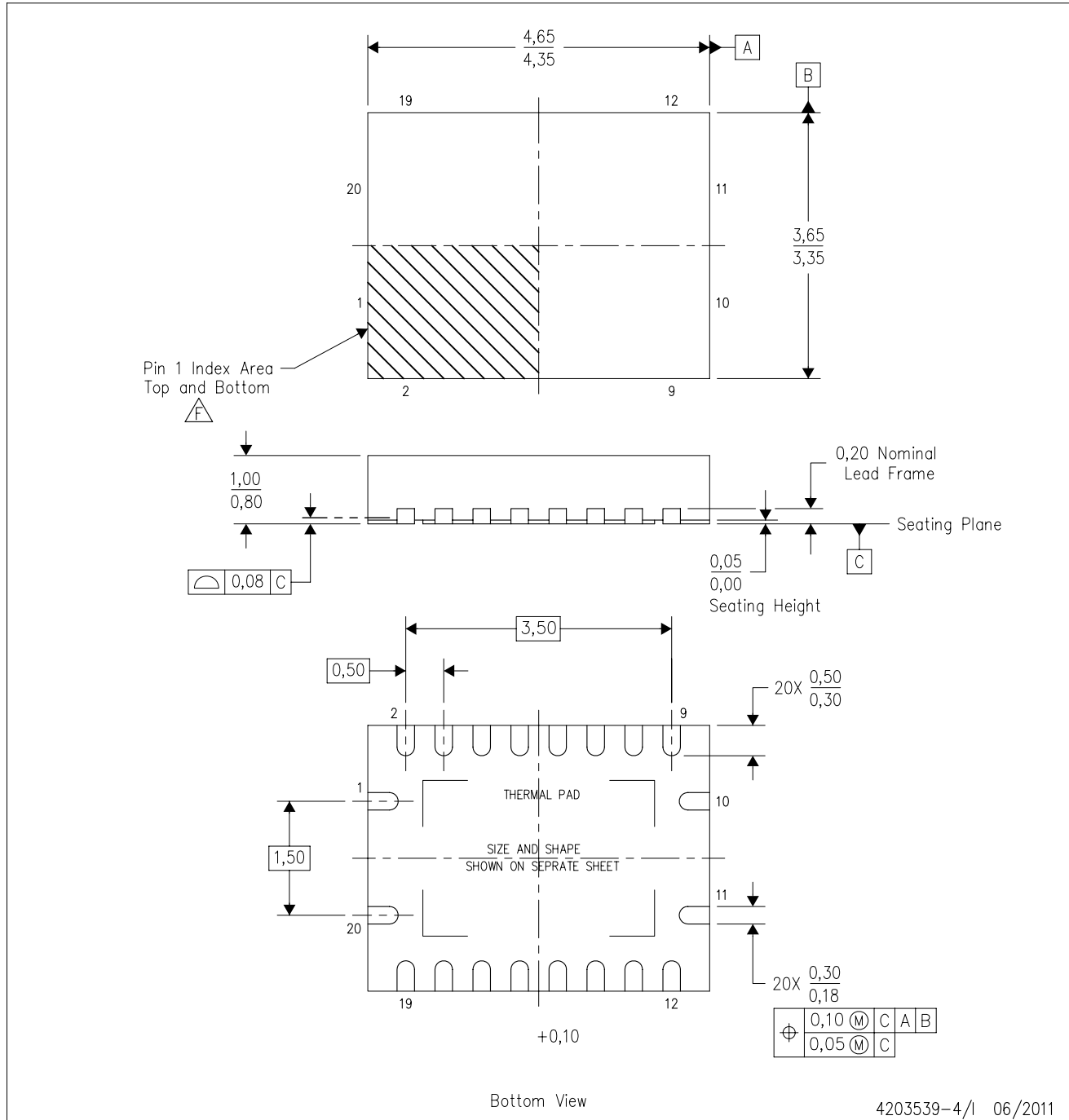


4040140/D 01/11

- NOTES:
- All linear dimensions are in inches (millimeters).
 - This drawing is subject to change without notice.
 - This package can be hermetically sealed with a metal lid.
 - Falls within JEDEC MS-004

RGY (R-PVQFN-N20)

PLASTIC QUAD FLATPACK NO-LEAD



4203539-4/I 06/2011

- NOTES:
- All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.
 - This drawing is subject to change without notice.
 - QFN (Quad Flatpack No-Lead) package configuration.
 - The package thermal pad must be soldered to the board for thermal and mechanical performance.
 - See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
 - Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
 - Package complies to JEDEC MO-241 variation BA.

RGY (R-PVQFN-N20)

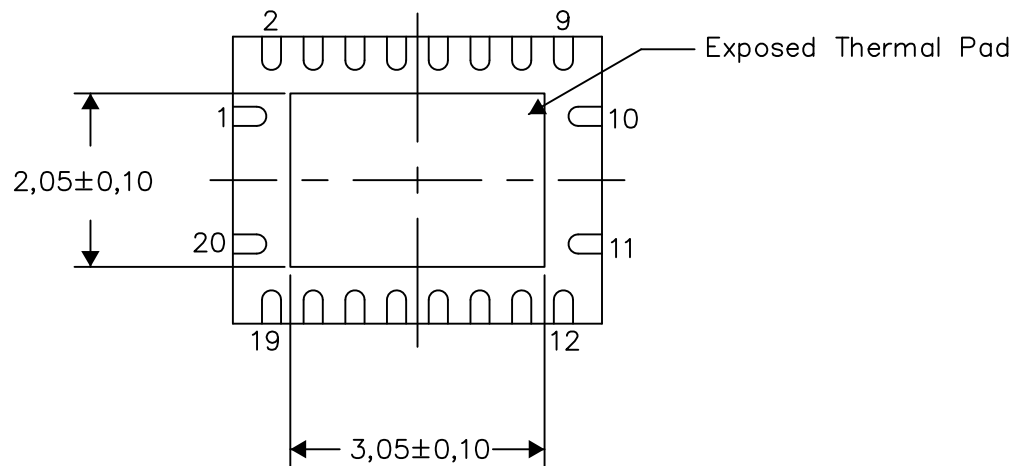
PLASTIC QUAD FLATPACK NO-LEAD

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No-Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Bottom View

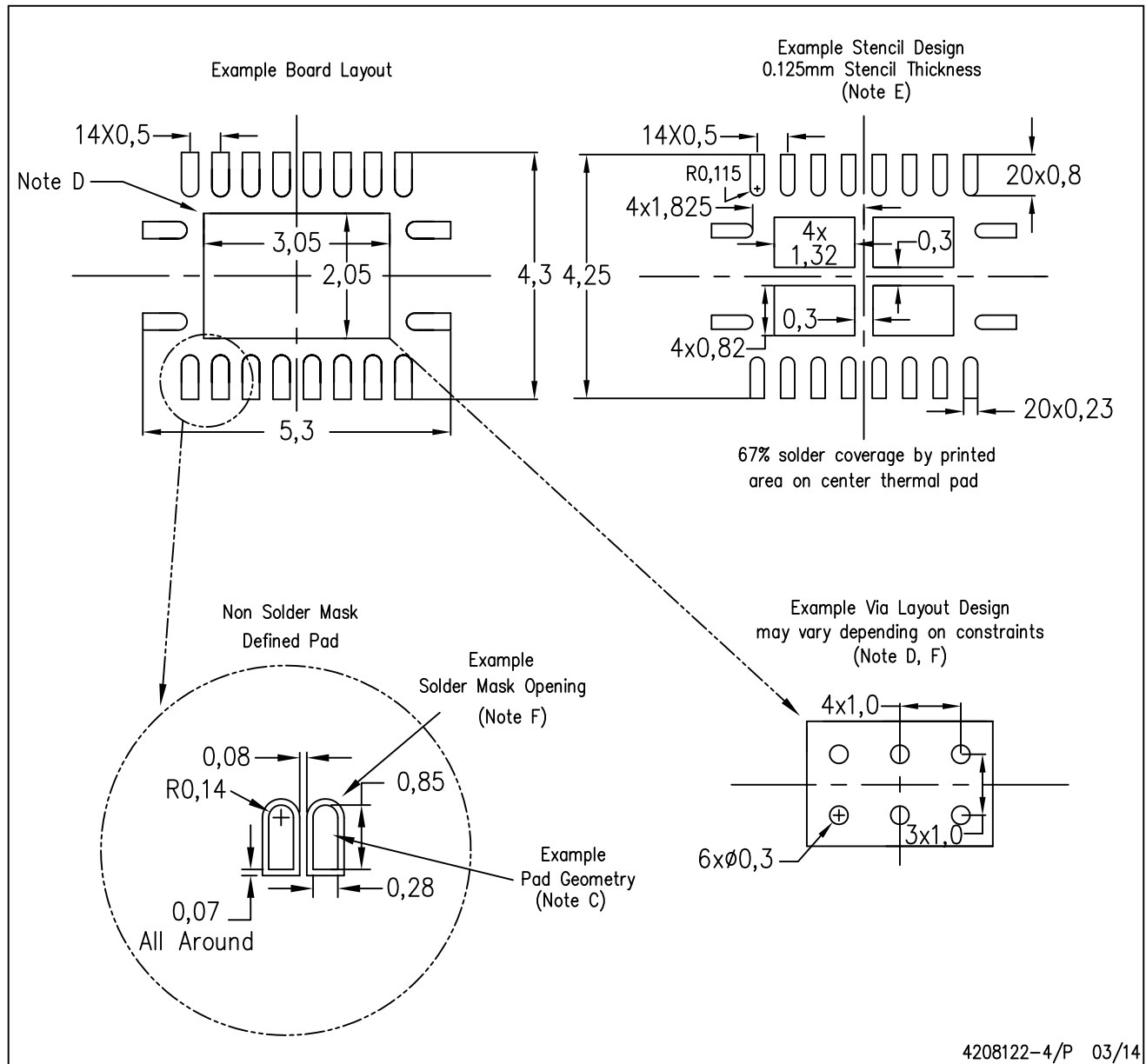
Exposed Thermal Pad Dimensions

4206353-4/P 03/14

NOTE: All linear dimensions are in millimeters

RGY (R-PVQFN-N20)

PLASTIC QUAD FLATPACK NO-LEAD



4208122-4/P 03/14

- NOTES:
- All linear dimensions are in millimeters.
 - This drawing is subject to change without notice.
 - Publication IPC-7351 is recommended for alternate designs.
 - This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat-Pack QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <<http://www.ti.com>>.
 - Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
 - Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

MECHANICAL DATA

NS (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

14-PINS SHOWN



DIM \ PINS **	14	16	20	24
A MAX	10,50	10,50	12,90	15,30
A MIN	9,90	9,90	12,30	14,70

4040062/C 03/03

- NOTES:
- A. All linear dimensions are in millimeters.
 - B. This drawing is subject to change without notice.
 - C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (www.ti.com/legal/termsofsale.html) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265
Copyright © 2019, Texas Instruments Incorporated